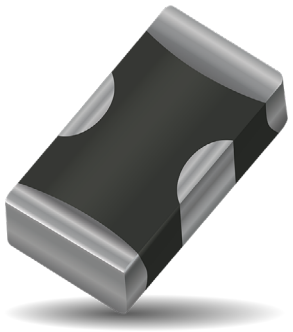
THE DATASHEET OF

V2F114C300Y1FDP

TransFeed®

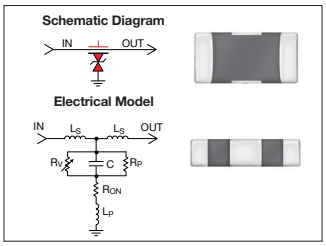
Multilayer Ceramic Transient Voltage Suppressors
TVS Protection and EMI Attenuation in a Single Chip



GENERAL DESCRIPTION

KYOCERA AVX has combined the best electrical characteristics of its TransGuard® Transient Voltage Suppressors (TVS) and its Feedthru Capacitors into a single chip for state-of-the-art overvoltage circuit protection and EMI reduction over a broad range of frequencies. This unique combination of multilayer ceramic construction in a feedthru configuration gives the circuit designer a single 0805 chip that responds to transient events faster than any TVS device on the market today, and provides significant EMI attenuation when in the off-state.

The reduction in parallel inductance, typical of the feedthru chip construction when compared to the construction of standard TVS or ceramic capacitor chips, gives the TransFeed® product two very important electrical advantages: (1) faster "turn-on" time. Calculated response times of <200 pSec are not unusual with this device, and measured response times range from 200 – 250 pSec. The TransFeed® "turn-on" characteristic is less than half that of an equivalent TransGuard® part — and TransGuards® clamp transient voltages faster than any other bipolar TVS solution such as diodes; (2) the second electrical advantage of lower parallel inductance, coupled with optimal series inductance, is the enhanced attenuation characteristics of the TransFeed® product. Not only is there significantly greater attenuation at a higher self-resonance frequency, but the roll-off characteristic becomes much flatter, resulting in EMI filtering over a much broader frequency spectrum. Typical applications include filtering/protection on Microcontroller I/O Lines, Interface I/O Lines, Power Line Conditioning and Power Regulation.



TYPICAL APPLICATIONS

- Fingerprint ID Circuit
- Magnetic Field Circuit
- LCD Dashboard Driver

Where designers are concerned with both transient voltage protection and EMI attenuation, either due to the electrical performance of their circuits or due to required compliance to specific EMC regulations, the TransFeed® product is an ideal choice.

GENERAL CHARACTERISTICS

- Operating Teperature: -55°C to +125°C
- Working Voltage: 5.6Vdc - 26 Vdc
- Case Size: 0805
- Energy Rating: 0.05 - 0.3J
- Current: 20 - 120A
- Max Feedthru Current: 0.5 - 1A

HOW TO ORDER

V	2	F	1	05	A	150	Y	2	E	D	P
Varistor	**Chip Size** 2 = 0805	**Feedthru Capacitor**	**No. of Elements**	**Voltage** 05 = 5.6VDC 09 = 9.0VDC 14 = 14.0VDC 18 = 18.0VDC 26 = 26.0VDC	**Energy Rating** X = 0.05J A = 0.1J C = 0.3J	**Varistor Clamping Voltage** 150 = 18V 200 = 22V 300 = 32V 400 = 42V 500 = 50V 600 = 60V	**Capacitance Tolerance** Y = +100/-50%	**DC Resistance** 1 = 0.150 Ohms 2 = 0.200 Ohms 3 = 0.250 Ohms	**Feedthru Current** D = 500 mA E = 750 mA F = 1.0 Amp	**Packaging Code Pcs./Reel** D = 1,000 R = 4,000 T = 10,000	**Termination Finish** P = Ni/Sn (Plated)

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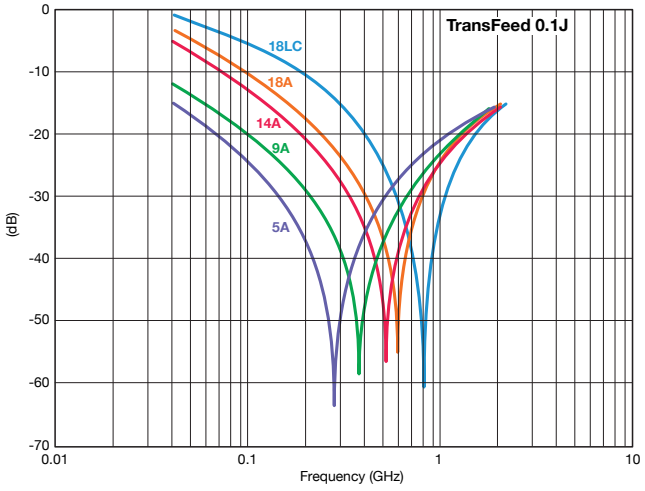
TRANSFEED ELECTRICAL SPECIFICATIONS

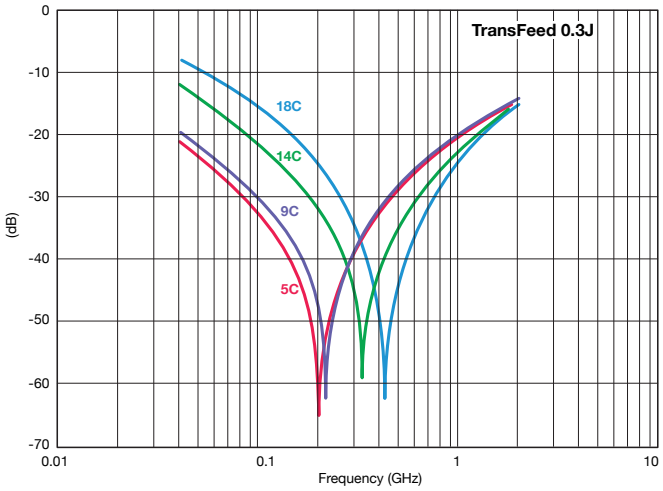
Part Number	Working Voltage (DC)	Working Voltage (AC)	Breakdown Voltage	Clamping Voltage	Maximum Leakage Current	Transient Energy Rating	Peak Current Rating	Typical Cap	DC Resistance	Maximum Feedthru Current
V2F105A150Y2E _ _	5.6	4.0	8.5±20%	18	35	0.10	30	800	0.200	0.75
V2F105C150Y1F _ _	5.6	4.0	8.5±20%	18	35	0.30	120	2500	0.150	1.00
V2F109A200Y2E _ _	9.0	6.4	12.7±15%	22	25	0.10	30	575	0.200	0.75
V2F109C200Y1F _ _	9.0	6.4	12.7±15%	22	25	0.30	120	1800	0.150	1.00
V2F114A300Y2E _ _	14.0	10.0	18.5±12%	32	15	0.10	30	300	0.200	0.75
V2F114C300Y1F _ _	14.0	10.0	18.5±12%	32	15	0.30	120	900	0.150	1.00
V2F118A400Y2E _ _	18.0	13.0	25.5±10%	42	10	0.10	30	200	0.200	0.75
V2F118C400Y1F _ _	18.0	13.0	25.5±10%	42	10	0.30	120	500	0.150	1.00
V2F118X500Y3D _ _	18.0	13.0	25.5±10%	50	10	0.05	20	75	0.250	0.50
V2F126C600Y2E _ _	26.0	18.0	34.5±10%	60	10	0.3	80	250	0.2	0.75

└Termination Finish Code
└Packaging Code

V_W (DC)	DC Working Voltage (V)
V_W (AC)	AC Working Voltage (V)
V_B	Typical Breakdown Voltage (V @ 1mADC)
V_B Tol	VB Tolerance is ± from Typical Value
V_C	Clamping Voltage (V @ 1A 8x20µS)
I_L	Maximum Leakage Current at the Working Voltage (µA)
E_T	Transient Energy Rating (J, 10x1000µS)
I_P	Peak Current Rating (A, 8x20µS)
Cap	Typical Capacitance (pF) @ 1MHz and 0.5 V
DCR	DC Resistance (Ohms)
I_{FT}	Maximum Feedthru Current (A)

dB Attenuation vs Frequency





DIMENSIONS

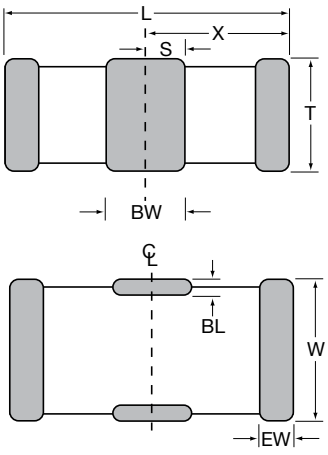
mm (inches)

	L	W	T	BW	BL	EW	X	S
0805	2.01 ± 0.20 (0.079 ± 0.008)	1.25 ± 0.20 (0.049 ± 0.008)	1.143 Max. (0.045 Max.)	0.46 ± 0.10 (0.018 ± 0.004)	0.18 + 0.25 -0.08 (0.007 + 0.010 -0.003)	0.25 ± 0.13 (0.010 ± 0.005)	1.02 ± 0.10 (0.040 ± 0.004)	0.23 ± 0.05 (0.009 ± 0.002)

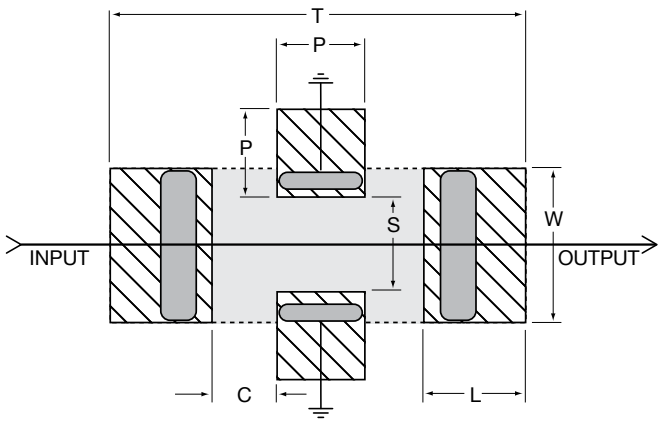
RECOMMENDED SOLDER PAD LAYOUT (Typical Dimensions)

mm (inches)

	T	P	S	W	L	C
0805	3.45 (0.136)	0.51 (0.020)	0.76 (0.030)	1.27 (0.050)	1.02 (0.040)	0.46 (0.018)



4 Pad Layout



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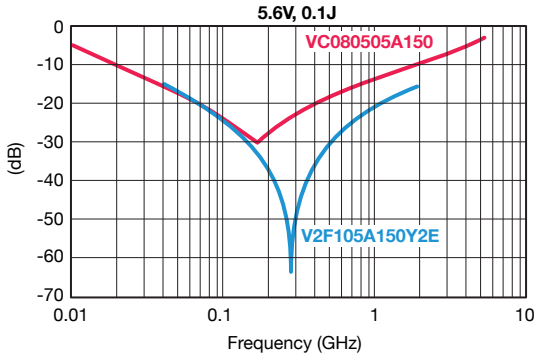
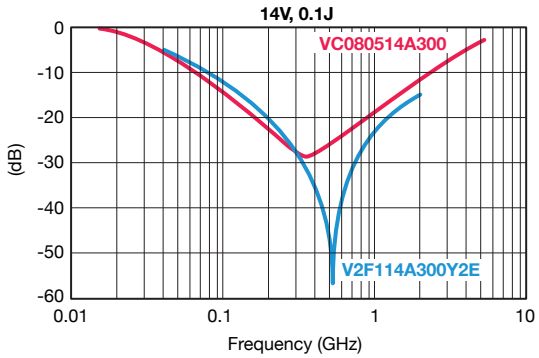
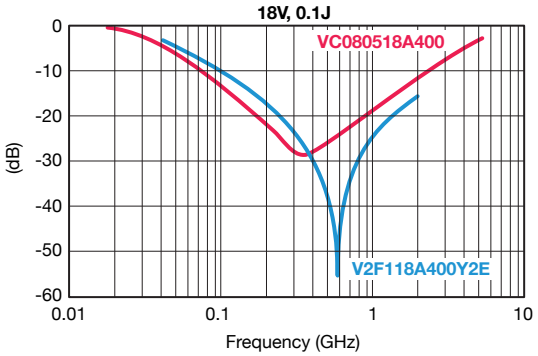
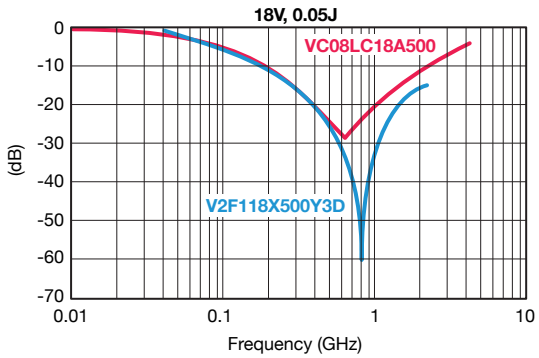
PERFORMANCE CHARACTERISTICS

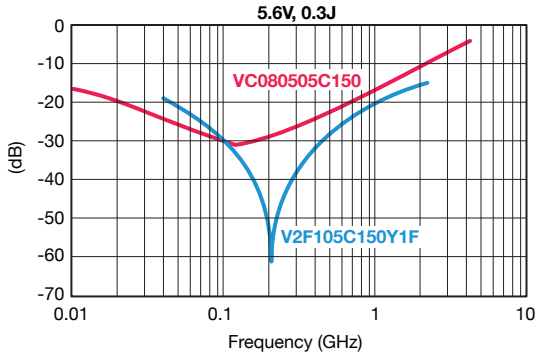
INSERTION LOSS COMPARISON (TRANSFEED® VS TRANSGUARD®) 0805 – DB VS FREQUENCY

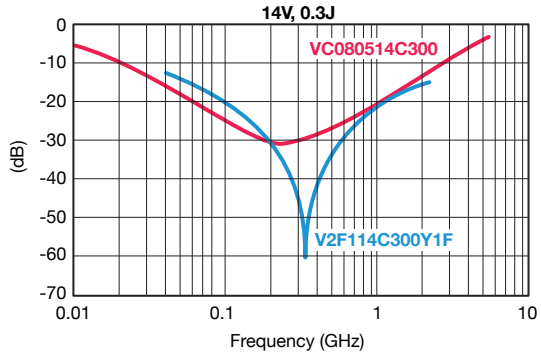


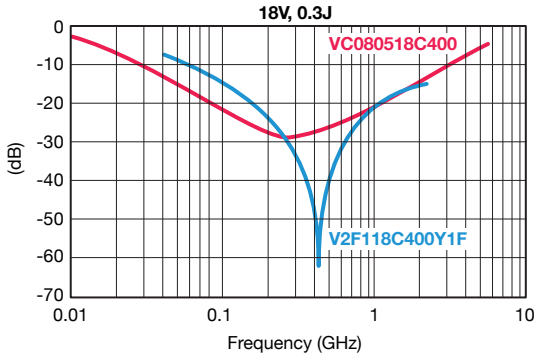






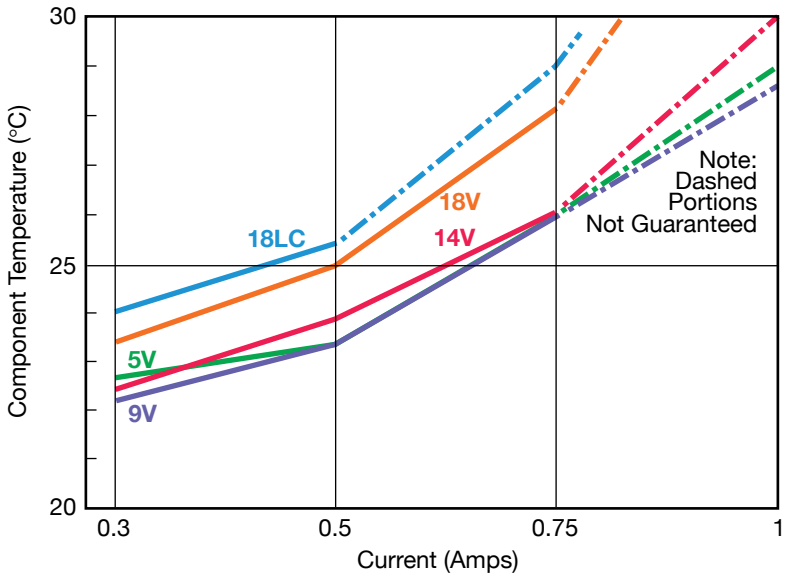




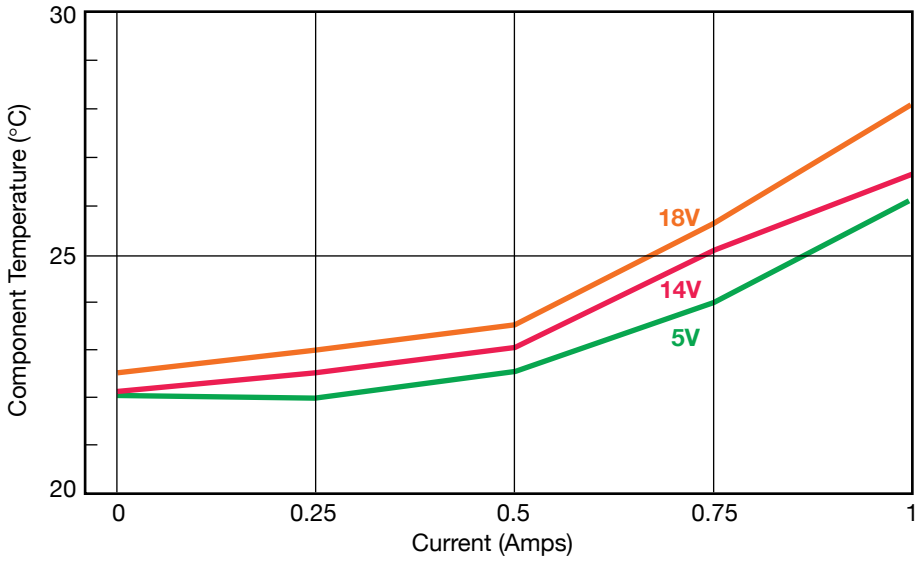


PERFORMANCE CHARACTERISTICS

CURRENT VS TEMPERATURE
0805 – 0.1 JOULE



CURRENT VS TEMPERATURE
0805 – 0.3 JOULE



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PERFORMANCE CHARACTERISTICS

FEEDTHRU VARISTORS

KYOCERA AVX Multilayer Feedthru Varistors (MLVF) are an ideal choice for system designers with transient strike and broadband EMI/RFI concerns.

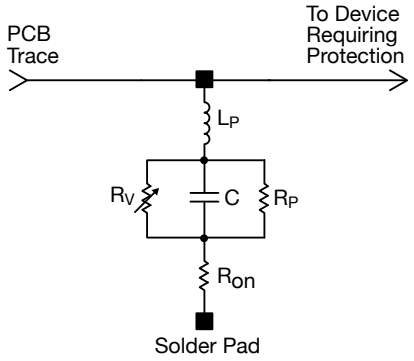
Feedthru Varistors utilize a ZnO varistor material and the electrode pattern of a feedthru capacitor. This combination allows the package advantage of the feedthru and material advantages of the ZnO dielectric to be optimized.

ZnO MLV Feedthrus exhibit electrical and physical advantages over standard ZnO MLVs. Among them are:

1. Faster Turn on Time
2. Broadband EMI attenuation
3. Small size (relative to discrete MLV and EMI filter schemes)

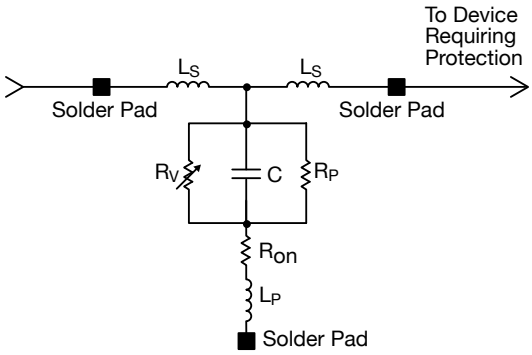
The electrical model for a ZnO MLV and a ZnO Feedthru MLV are shown below. The key difference in the model for the Feedthru is a transformation in parallel to series inductance. The added series inductance helps lower the injected transient peak current (by 2πfL) resulting in an additional benefit of a lower clamping voltage. The lowered parallel inductance decreases the turn on time for the varistor to <250ps.

Discrete MLV Model



Where: R_V = Voltage Variable resistance (per VI curve)
$R_p \geq 10^{12}\ \Omega$
C = defined by voltage rating and energy level
R_{on} = turn on resistance
L_p = parallel body inductance

Discrete MLVF Model



Where: R_V = Voltage Variable resistance (per VI curve)
$R_p \geq$ Body IR
C = defined by voltage rating and energy level
R_{on} = turn on resistance
L_p = minimized parallel body inductance
L_S = series body inductance

PERFORMANCE CHARACTERISTICS

APPLICATIONS
- EMI Suppression
- Broadband I/O Filtering
- Vcc Line Conditioning

FEATURES
- Small Size
- Low ESR
- Ultra-fast Response Time
- Broad S21 Characteristics

MARKET SEGMENTS
- Computers
- Automotive
- Power Supplies
- Multimedia Add-On Cards
- Bar Code Scanners
- Remote Terminals
- Medical Instrumentation
- Test Equipment
- Transceivers
- Cellular Phones / Pagers

TYPICAL CIRCUITS REQUIRING TRANSIENT VOLTAGE PROTECTION AND EMI FILTERING

The following applications and schematic diagrams show where TransFeed® TVS/ EMI filtering devices might be used:

- System Board Level Interfaces: (Fig. 1)
  - Digital to RF
  - Analog to Digital
  - Digital to Analog
- Voltage Regulation (Fig. 2)
- Power Conversion Circuits (Fig. 3)
- GaAs FET Protection (Fig. 4)

Fig. 1 – System Interface

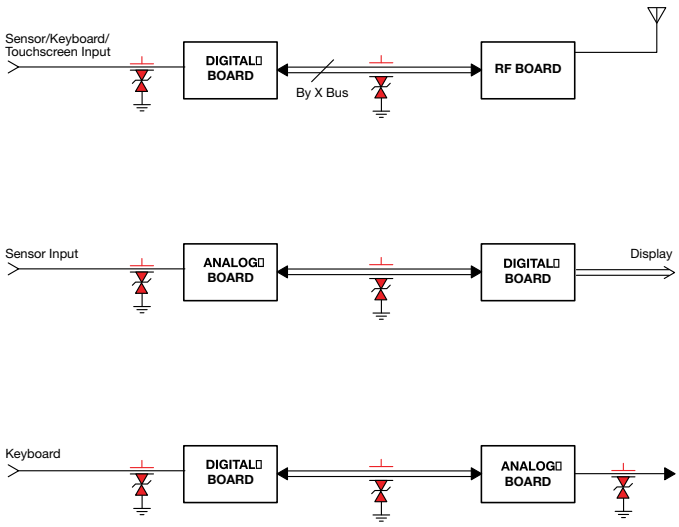


Fig. 2 – Voltage Regulators

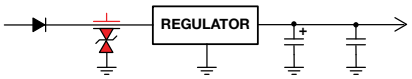


Fig. 3 – Power Conversion Circuits/Power Switching Circuits

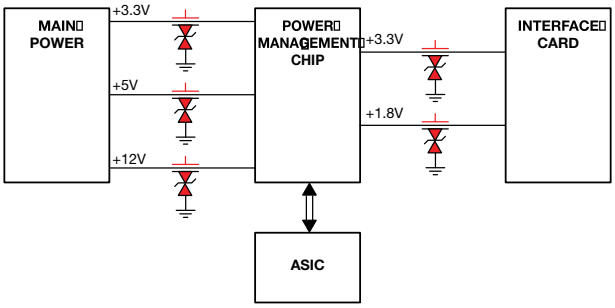
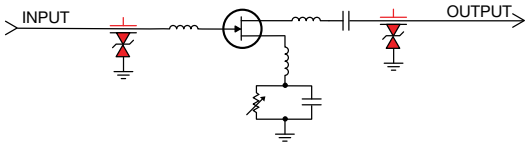


Fig. 4 – GaAs FET Protection



SPECIFICATION COMPARISON

MLVF 0805	PARAMETER		MLV 0805
5ph	Ls	typical	N/A
<600nh	Lp	typical	<1.5nh
<0.025Ω	Ron	typical	<0.1Ω
100pf to 2.5nf	C	typical	100pf to 5.5nf
see VI curves	Rv	typical	see VI curves
>0.25 x 1012Ω	Rp	typical	>1 x 1012Ω
<250ps	Typical turn on time Typical frequency response		<500ps

A comparison table showing typical element parameters and resulting performance features for MLV and MLVF is shown above.

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